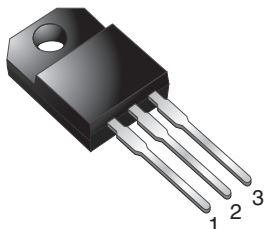
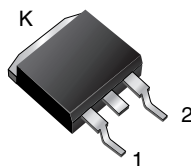
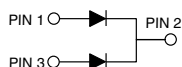
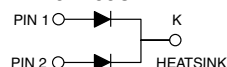


# Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance

**ITO-220AB**

**D<sup>2</sup>PAK (TO-263AB)**

**MF10H100CT**

**MB10H100CT**


## FEATURES

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D<sup>2</sup>PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
**HALOGEN**  
**FREE**  
Available

## TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

## MECHANICAL DATA

**Case:** ITO-220AB, D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code e.g. A, B,.....)

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 and HM3 suffix meets JESD 201 class 2 whisker test

**Polarity:** as marked

**Mounting Torque:** 10 in-lbs maximum

## PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 5 A
$V_{RRM}$	100 V
$I_{FSM}$	150 A
$V_F$	0.61 V
$I_R$	3.5 $\mu$ A
$T_J$ max.	175 °C
Package	ITO-220AB, D <sup>2</sup> PAK (TO-263AB)
Circuit configuration	Common cathode

## MAXIMUM RATINGS ( $T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	MB10H100CT	MF10H100CT	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	100		V
Working peak reverse voltage	$V_{RWM}$	100		
Maximum DC blocking voltage	$V_{DC}$	100		
Maximum average forward rectified current at $T_C = 105$ °C	$I_{F(AV)}$	total device	10	A
		per diode	5.0	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	150		
Peak repetitive reverse current per diode at $t_p = 2.0$ $\mu$ s, 1 kHz	$I_{RRM}$	0.5		
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000		V/ $\mu$ s
Operating junction and storage temperature range	$T_J, T_{STG}$	-65 to +175		°C
Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1$ min	$V_{AC}$	1500		V

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT
Maximum instantaneous forward voltage per diode	$V_F^{(1)}$	$I_F = 5\text{ A}$	$T_J = 25\text{ }^{\circ}\text{C}$	0.76	V
		$I_F = 5\text{ A}$	$T_J = 125\text{ }^{\circ}\text{C}$	0.61	
		$I_F = 10\text{ A}$	$T_J = 25\text{ }^{\circ}\text{C}$	0.85	
		$I_F = 10\text{ A}$	$T_J = 125\text{ }^{\circ}\text{C}$	0.71	
Maximum reverse current per diode	$I_R^{(1)}$	Rated $V_R$	$T_J = 25\text{ }^{\circ}\text{C}$	3.5	$\mu\text{A}$
			$T_J = 100\text{ }^{\circ}\text{C}$	4.5	mA

**Notes**

- (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle  
(2) Pulse test: pulse width  $\leq 40\text{ ms}$

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)				
PARAMETER	SYMBOL	MB10H100CT	MF10H100CT	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	2.2	5.2	$^{\circ}\text{C/W}$

<b>ORDERING INFORMATION</b>					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	MF10H100CTHE3_B/P	1.79	P	50/tube	Tube
D <sup>2</sup> PAK (TO-263AB)	MB10H100CTHM3/I	1.35	I	800/reel	Tape and reel

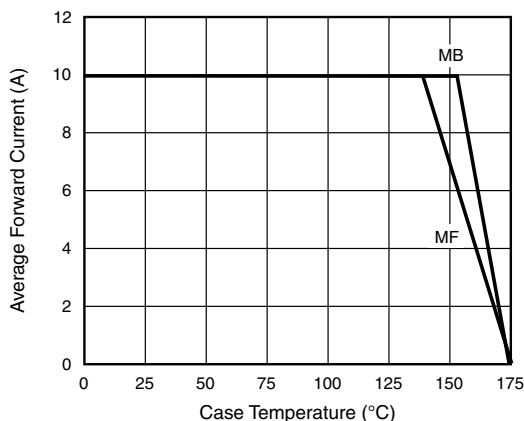
**RATINGS AND CHARACTERISTICS CURVES** ( $T_C = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)


Fig. 1 - Forward Current Derating Curve Per Diode

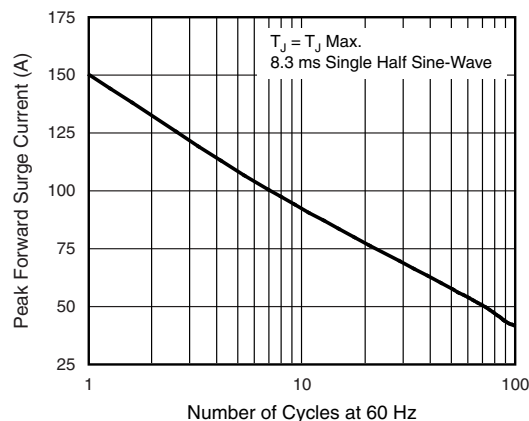


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

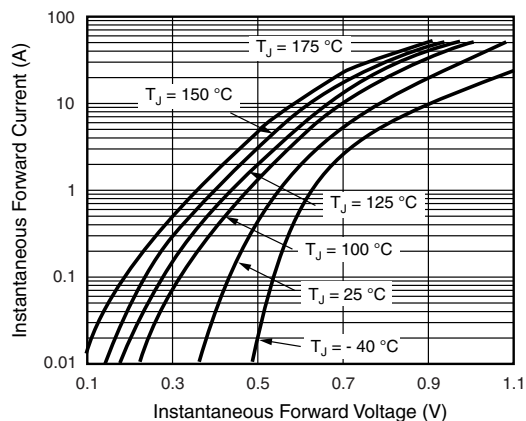


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

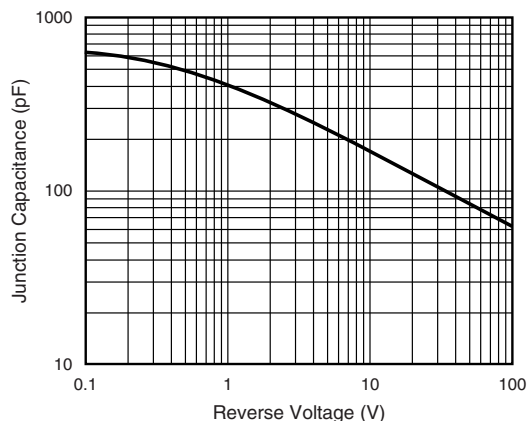


Fig. 5 - Typical Junction Capacitance Per Diode

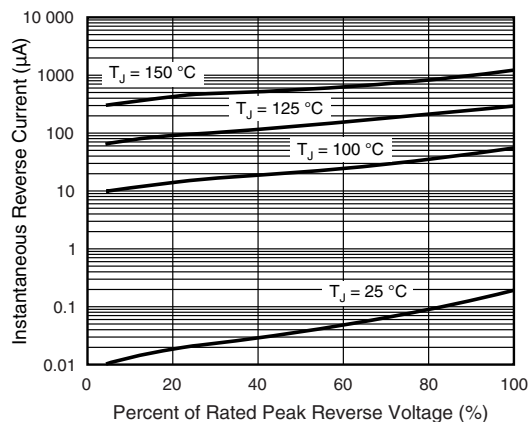


Fig. 4 - Typical Reverse Characteristics Per Diode

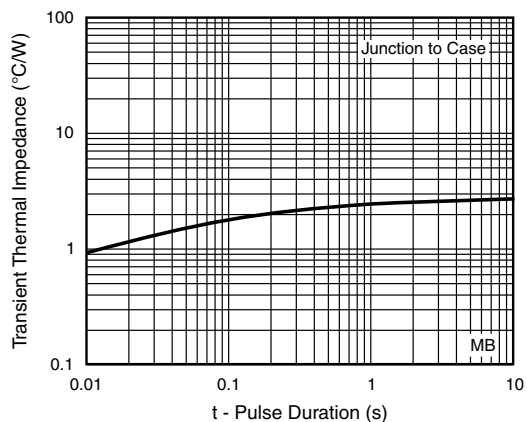


Fig. 6 - Typical Transient Thermal Impedance Per Diode

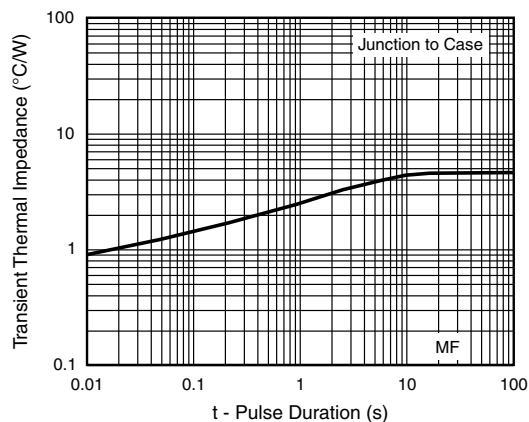
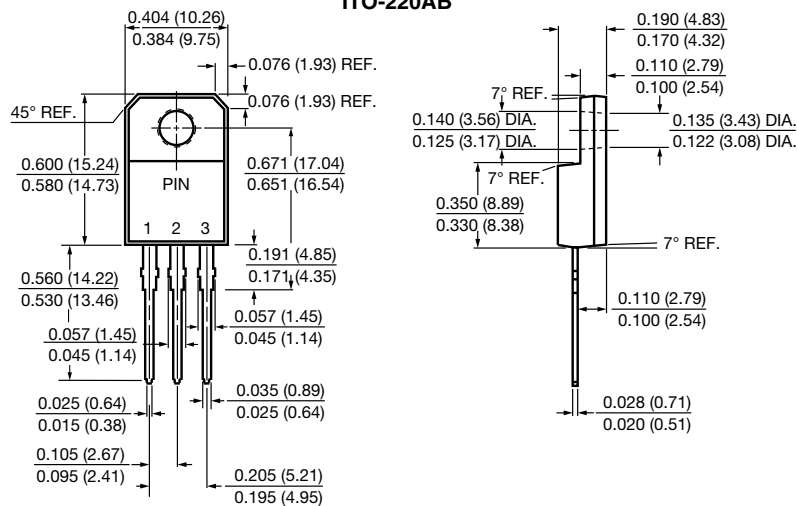


Fig. 7 - Typical Transient Thermal Impedance Per Diode

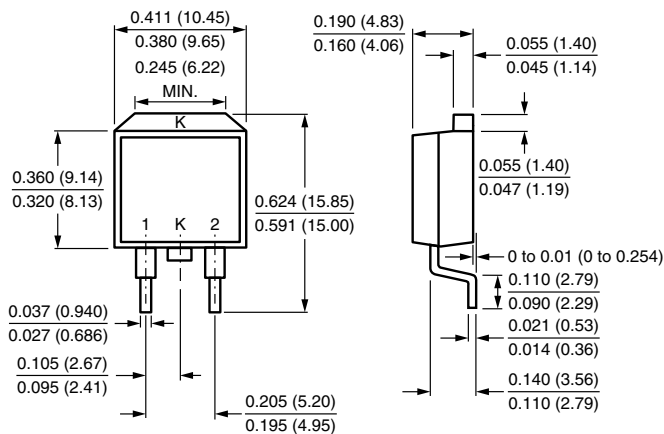


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

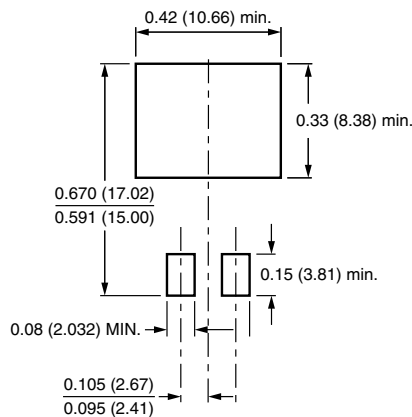
ITO-220AB



D<sup>2</sup>PAK (TO-263AB)



Mounting Pad Layout





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